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Low dimensional plasmonic spectroscopy through inversion of the far infrared detection problem

**G. C. Dyer¹, G. R. Aizin², A. D. Grine¹, D. Bethke¹, X. Shi³, B. V. Olsen¹,
J. L. Reno¹, S. D. Hawkins¹, J. F. Klem¹, W. Pan¹, and E. A. Shaner¹**

¹Sandia Nat'l Labs, ²Kingsborough College (CUNY), ³The Univ. of Texas at Dallas

**SPIE D+CS 2016: Terahertz Physics, Devices, and Systems X
THz: Advanced Concepts I, Paper 9856-6, 4/17/16**

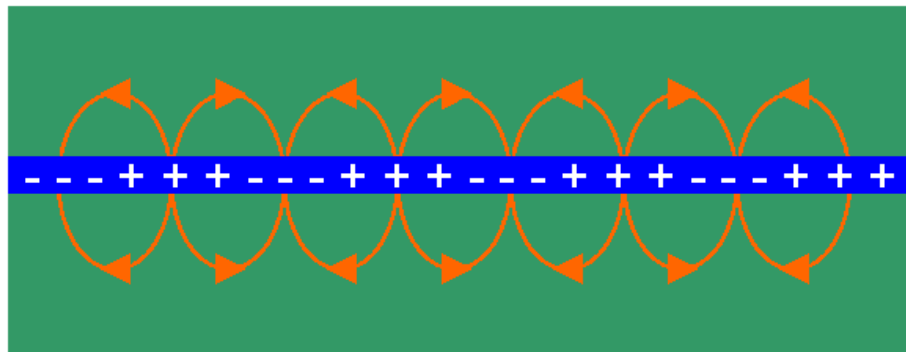


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Outline

- Low dimensional far infrared plasmonics
- GaAs/AlGaAs 2D plasmonic resonators
 - Strong coupling of 2D plasmonic resonators
 - Coupled oscillator & transmission line models
 - Active control of plasmonic crystal band structure
- Edge photoresponse in inverted InAs/GaSb double quantum wells

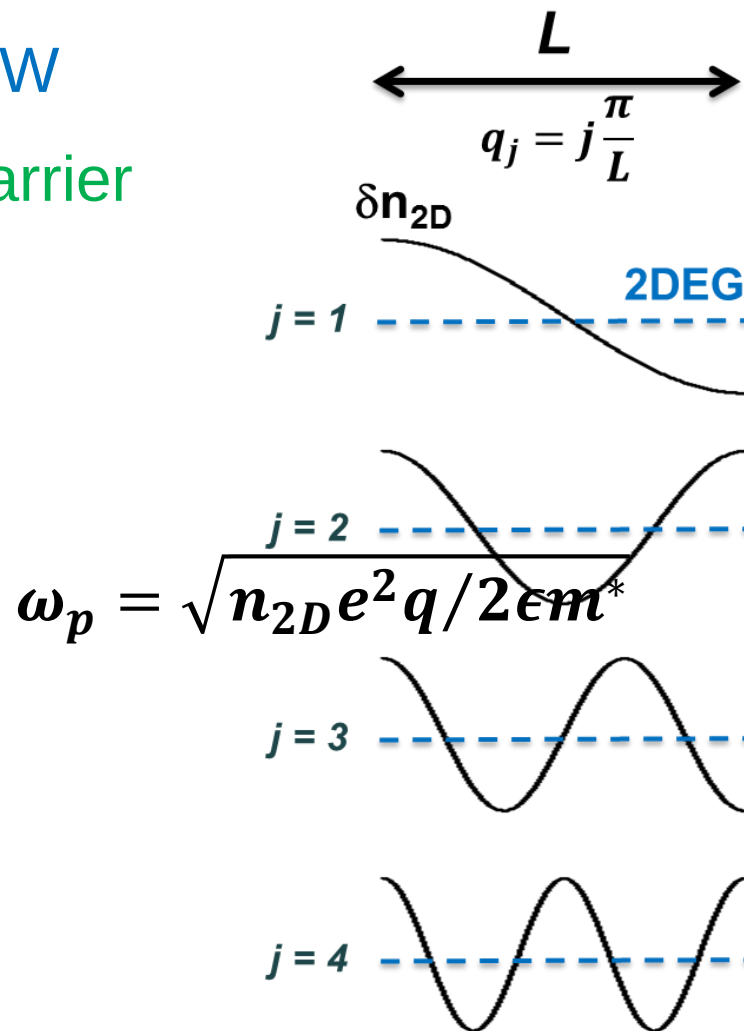
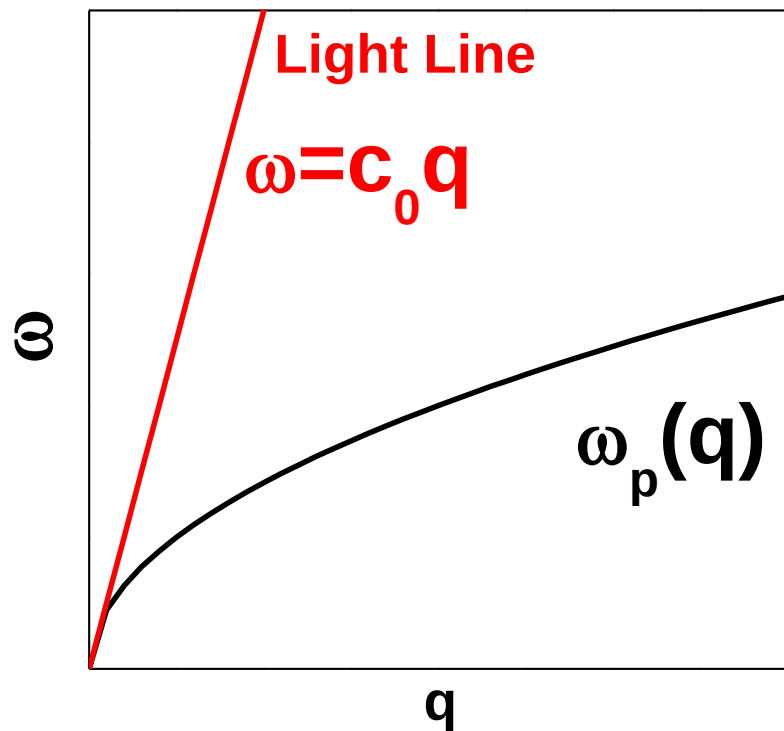
Low Dimensional Plasmonics



barrier

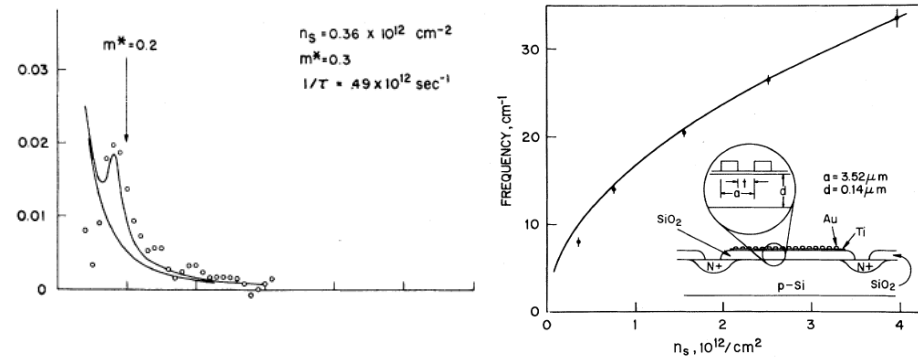
QW

barrier



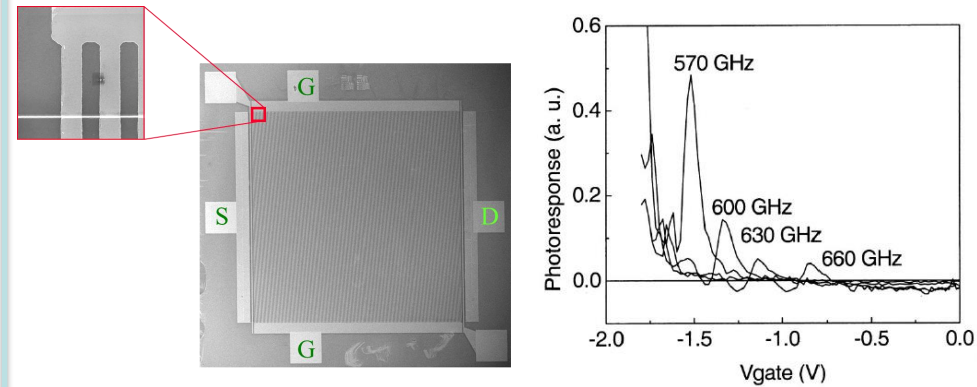
FIR 2D Plasmonic Systems

Grating Gated Si MOSFETs



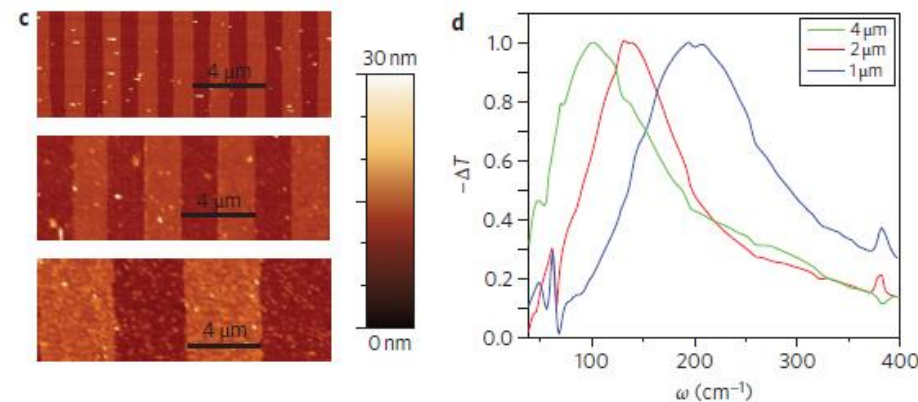
S.J. Allen *et al.*, *PRL* **38**, 980 (1977)

Grating Gated GaAs/AlGaAs HEMTs



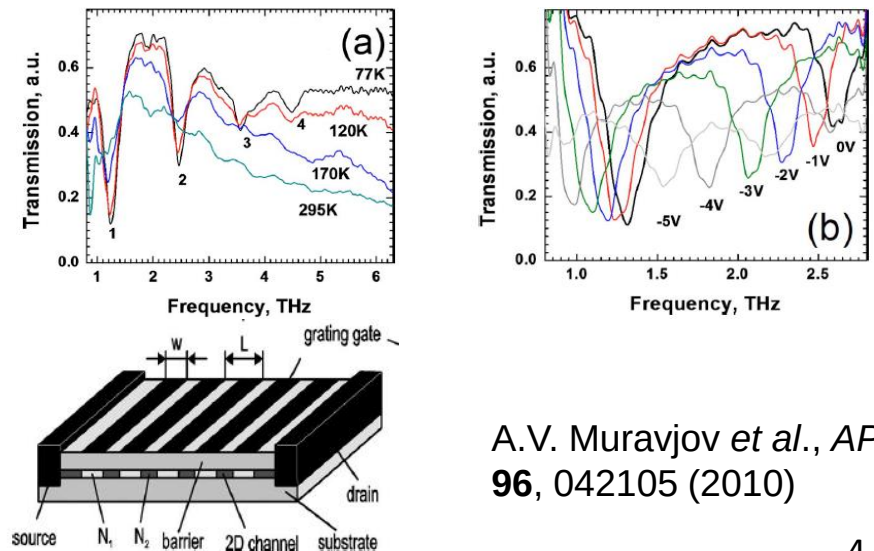
X.G. Peralta *et al.*, *APL* **81**, 1627 (2002)

Graphene Gratings



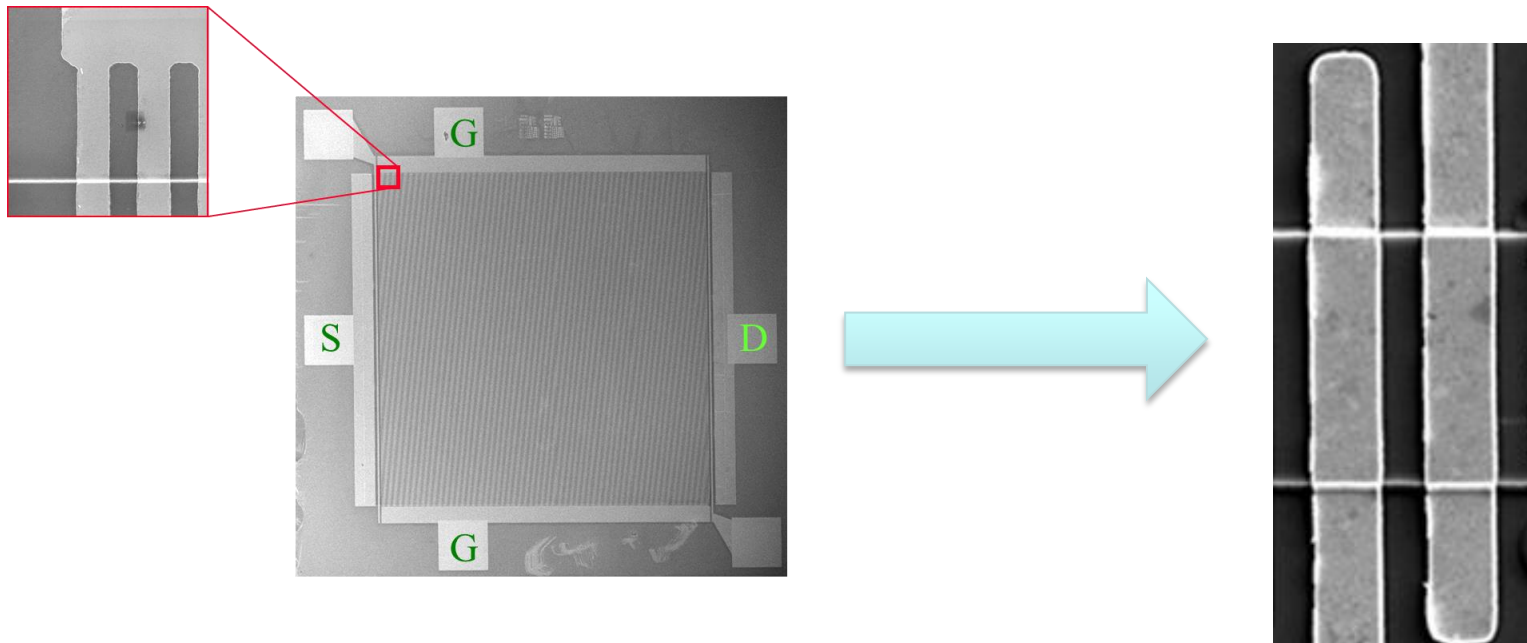
L. Ju *et al.*, *Nat. Nano.* **6**, 630 (2011)

Grating Gated GaN/AlGaN HEMTs



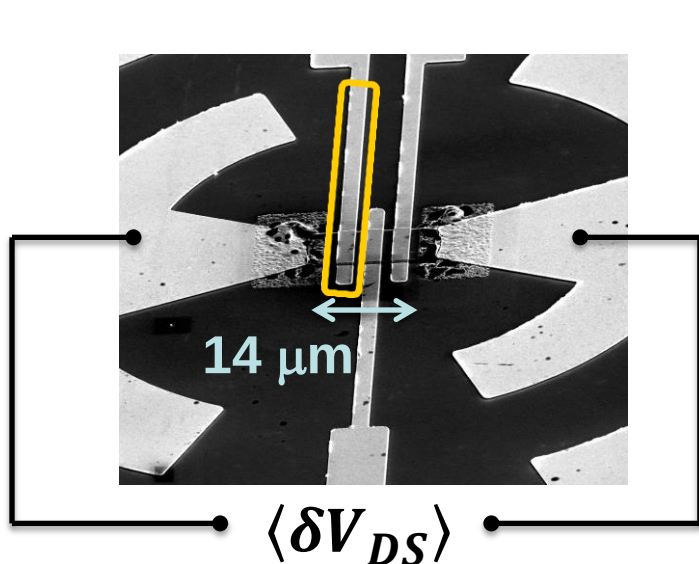
A.V. Muravjov *et al.*, *APL* **96**, 042105 (2010)

From Plasmonic Arrays to Elements



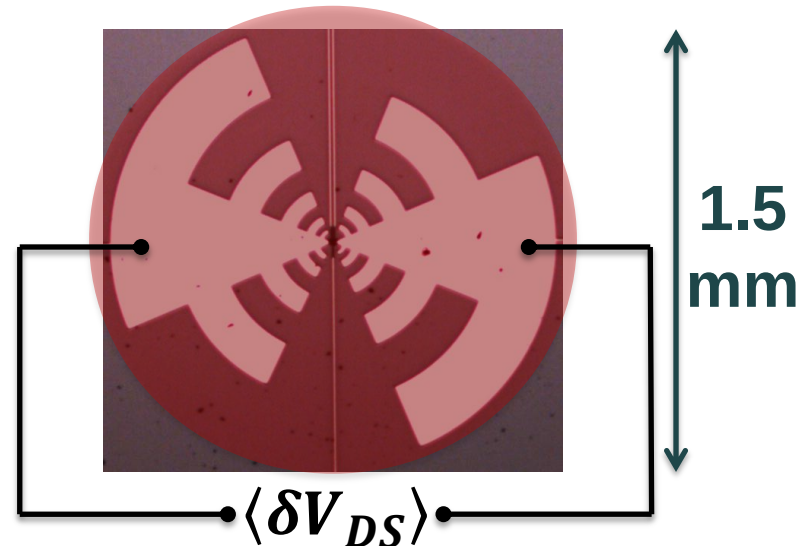
- Plasmon-plasmon coupling
- Plasmonic dispersion in coupled structures
- Plasmon damping & coherence length

Integrated 2D Plasmonic Devices

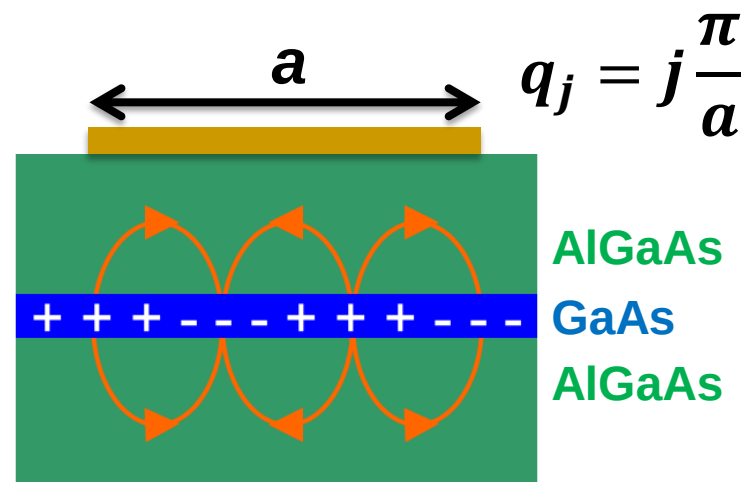


$\vec{E}$
 $\vec{S}$
 $\vec{B}$

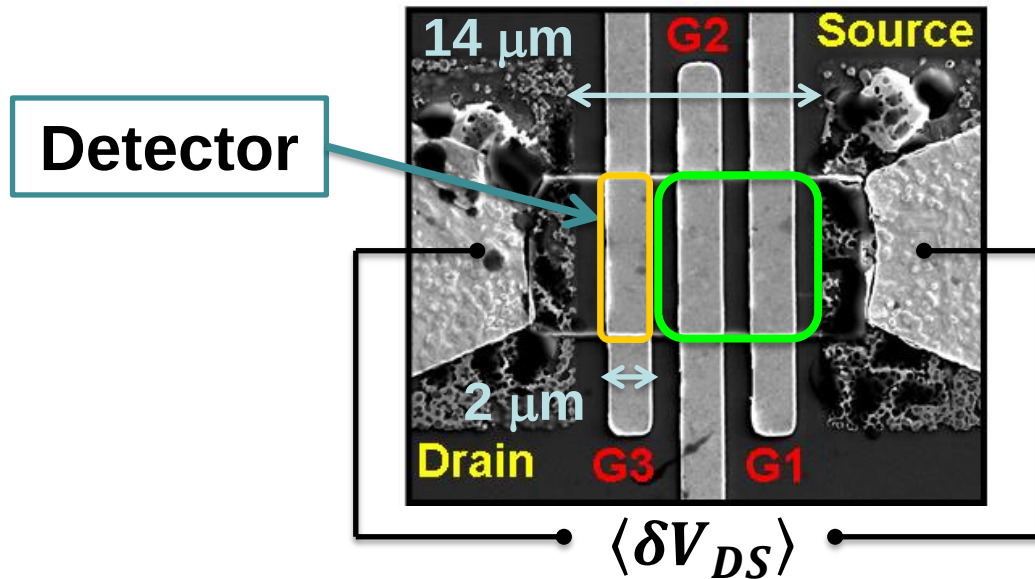
0.1 - 0.5
THz



- **Detection:** depleted 2DEG
- **Coupling:** log-periodic antenna
- **Resonance:** 2D plasmon wavelength set by device geometry



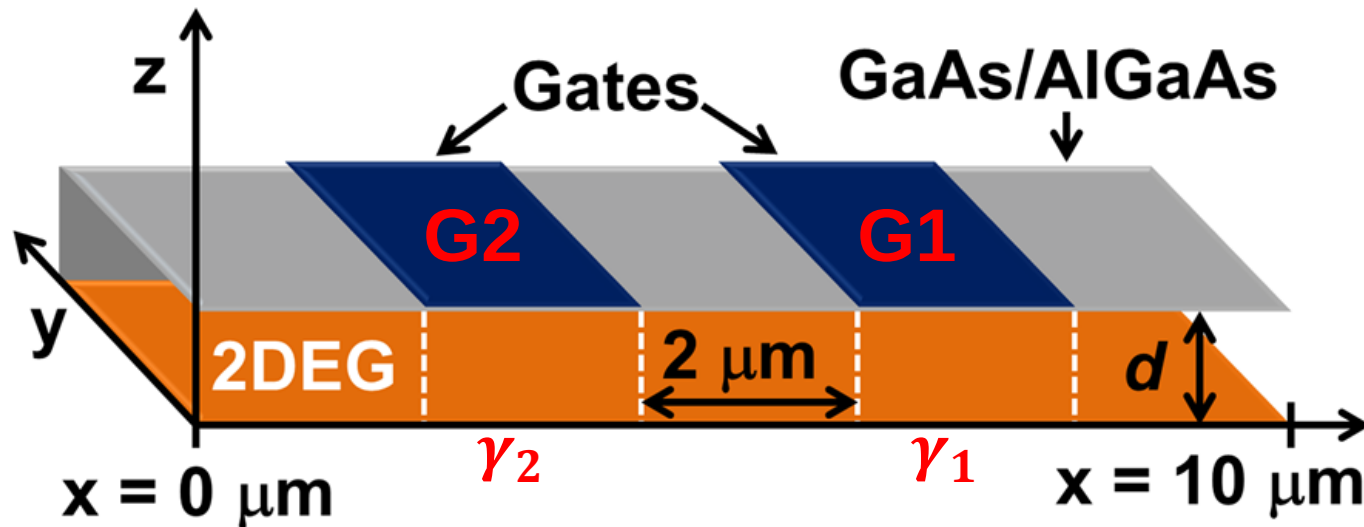
Inhomogeneous 2DEG Structures



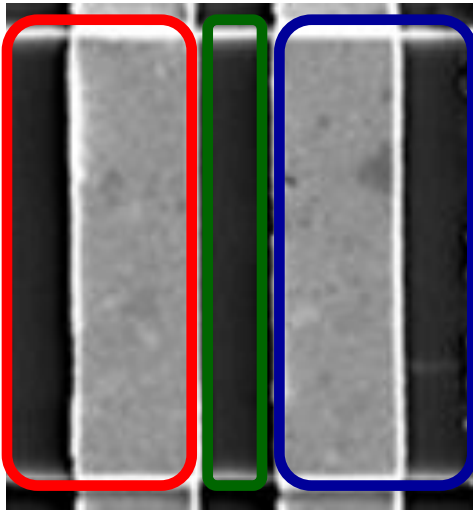
Normalized 2DEG Density

$$\gamma_1 = \frac{V_{th} - V_{G1}}{V_{th}}$$

$$\gamma_2 = \frac{V_{th} - V_{G2}}{V_{th}}$$



Coupled Resonator Description

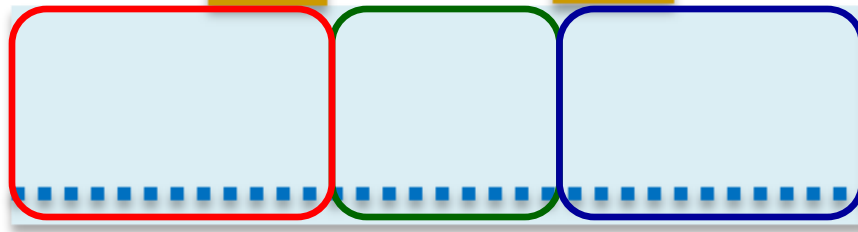


Coupling

$G2$

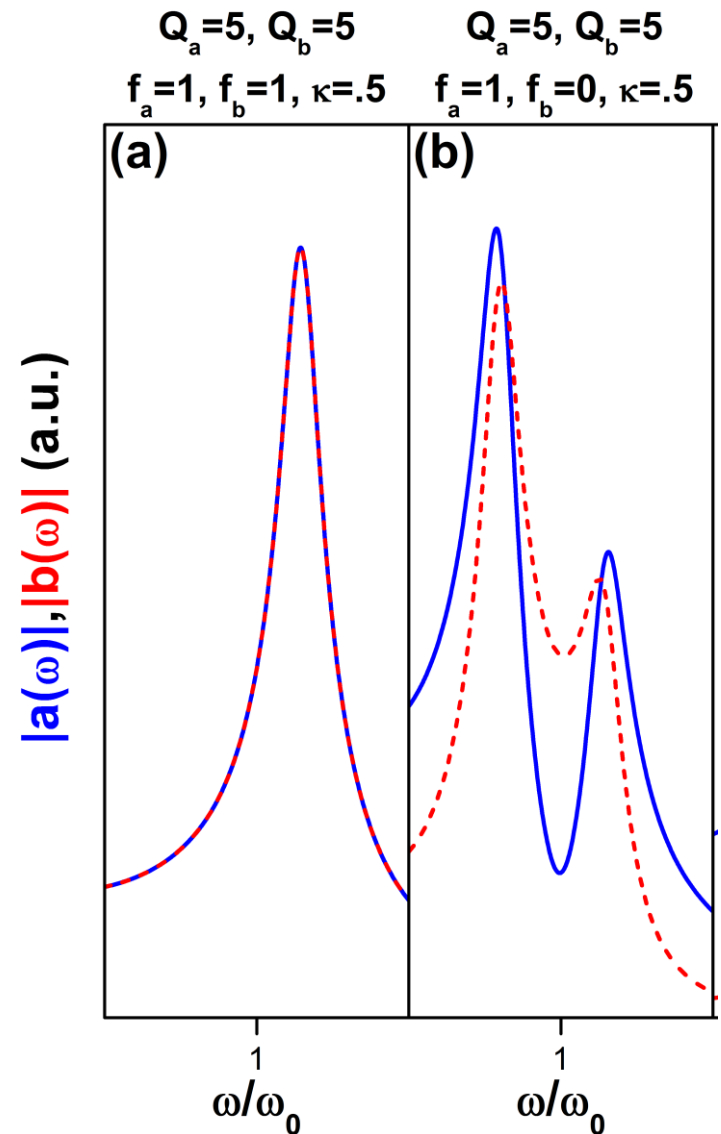
(κ)

$G1$

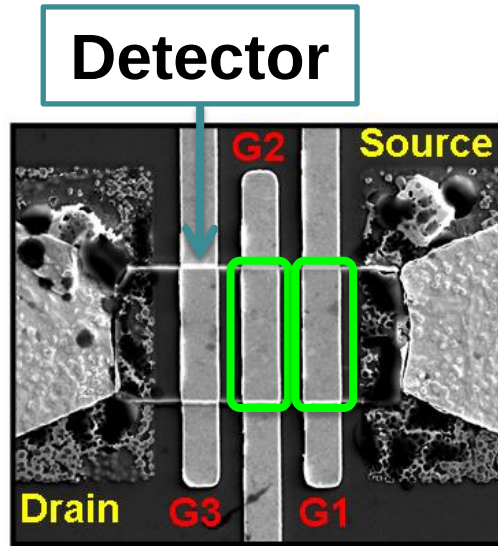


Oscillator *a*
($a(\omega), \omega_a, f_a, Q_a$)

Oscillator *b*
($b(\omega), \omega_b, f_b, Q_b$)

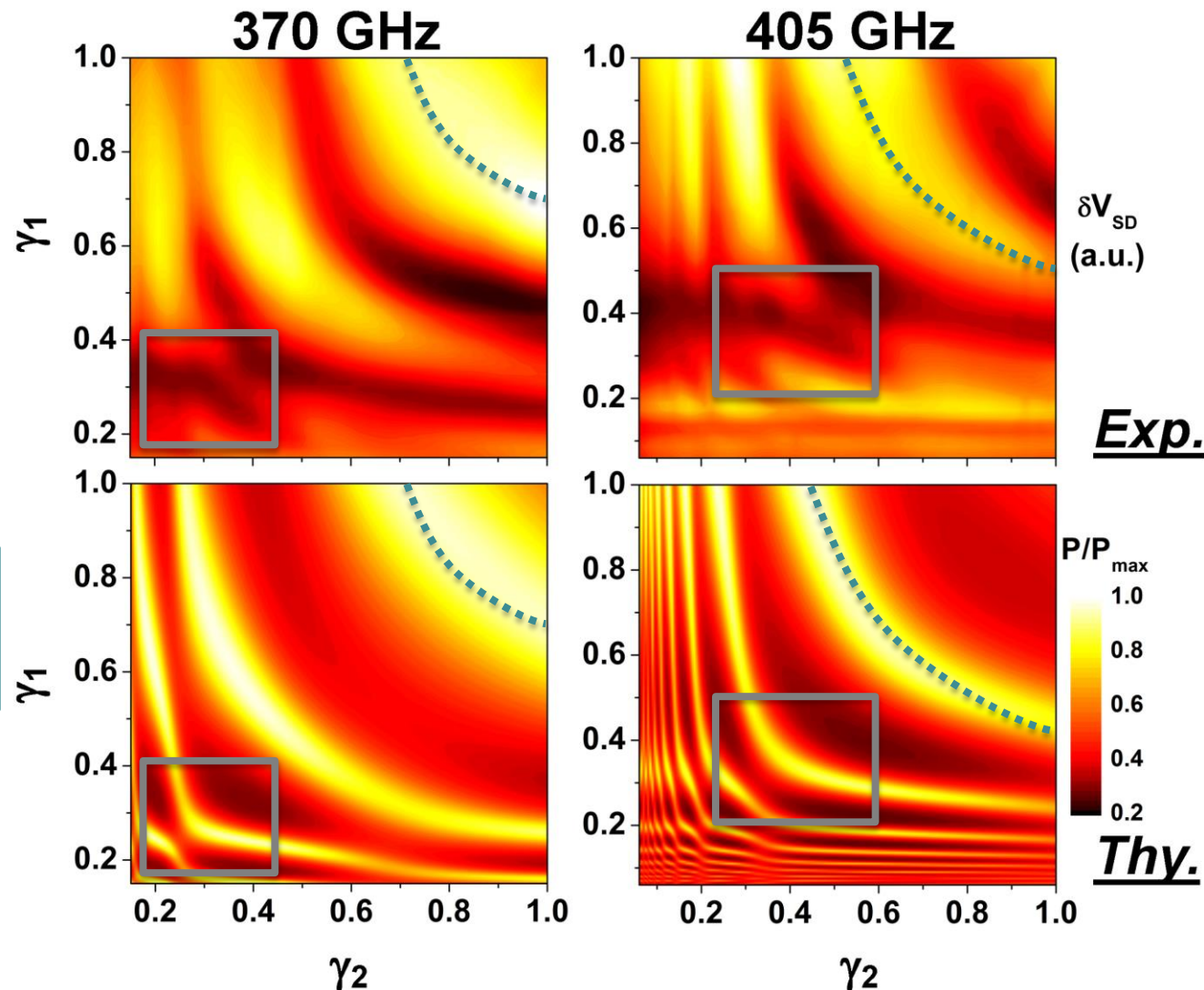


Coherent Plasmonic Coupling

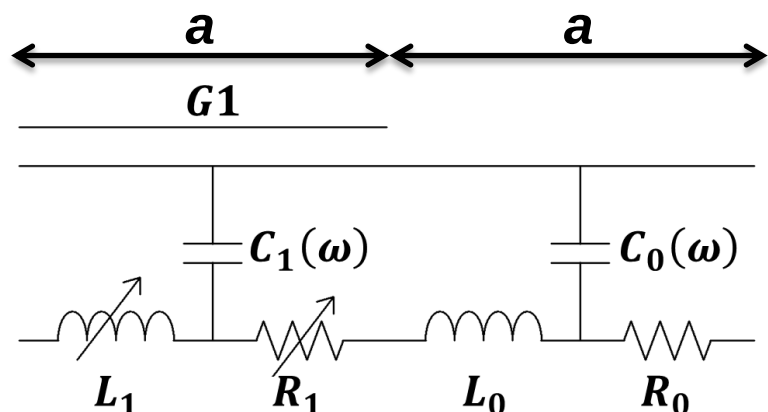


$$\gamma_{1,2} = \frac{V_{th} - V_{G1,G2}}{V_{th}}$$

Strongly coupled
2D plasmonic
resonators



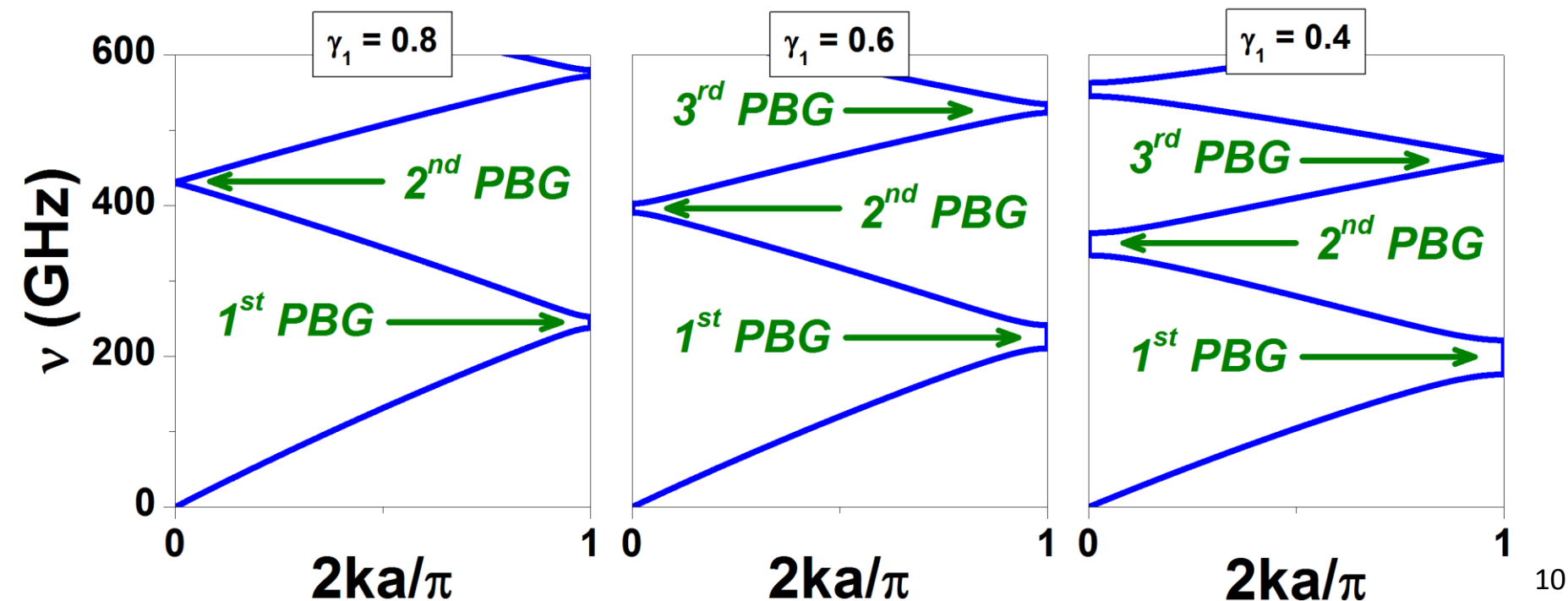
Plasmonic Crystal Band Structure



1D Kronig-Penney:

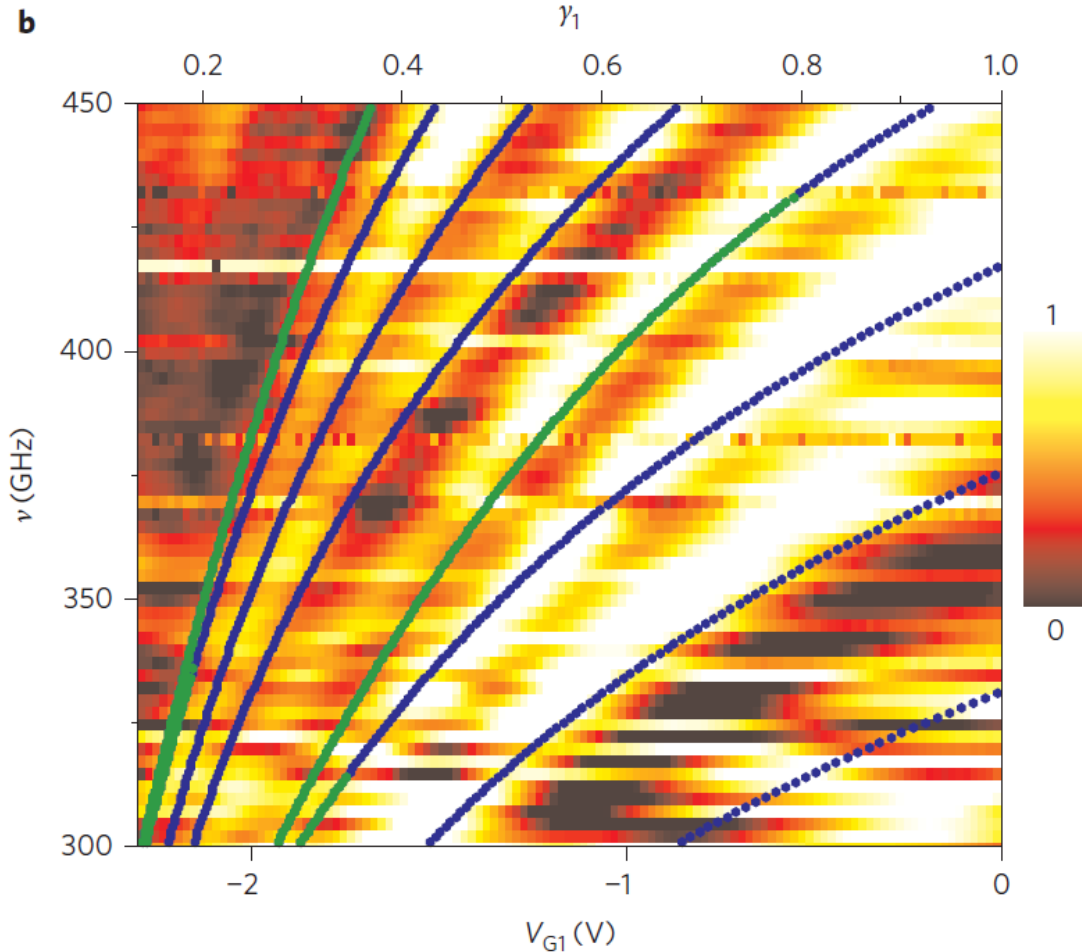
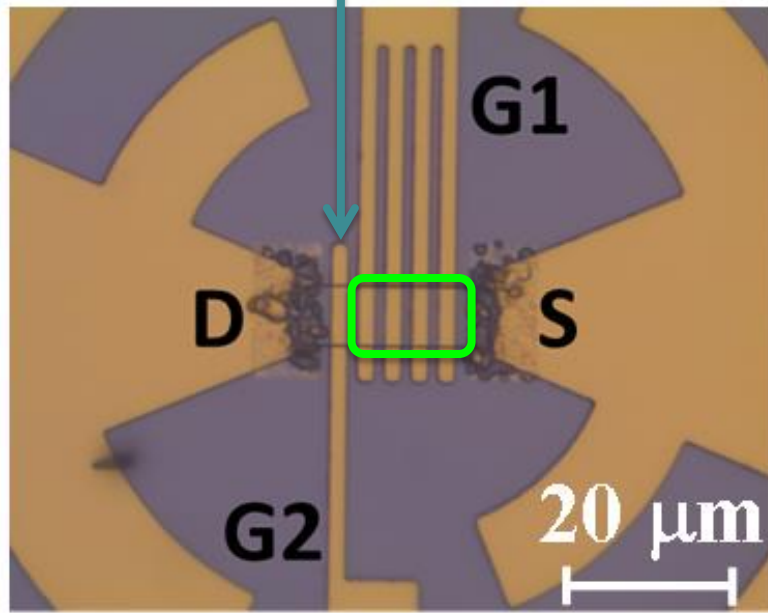
$$\cos 2k_B a =$$

$$\cos q_0 a \cos q_1 a - \frac{1}{2} \left(\frac{Z_0}{Z_1} + \frac{Z_1}{Z_0} \right) \sin q_0 a \sin q_1 a$$



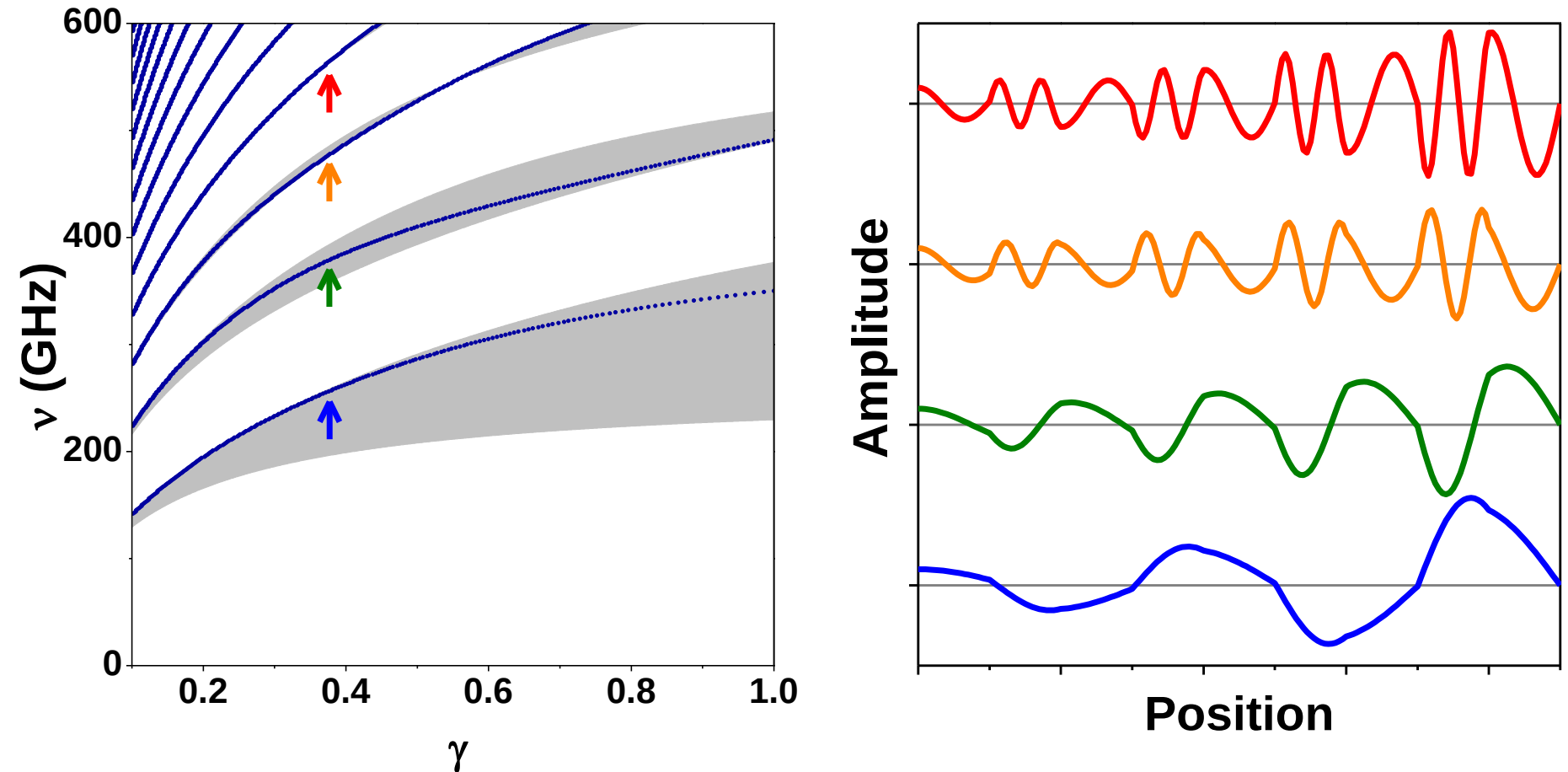
Four Period Plasmonic Crystal

Detector



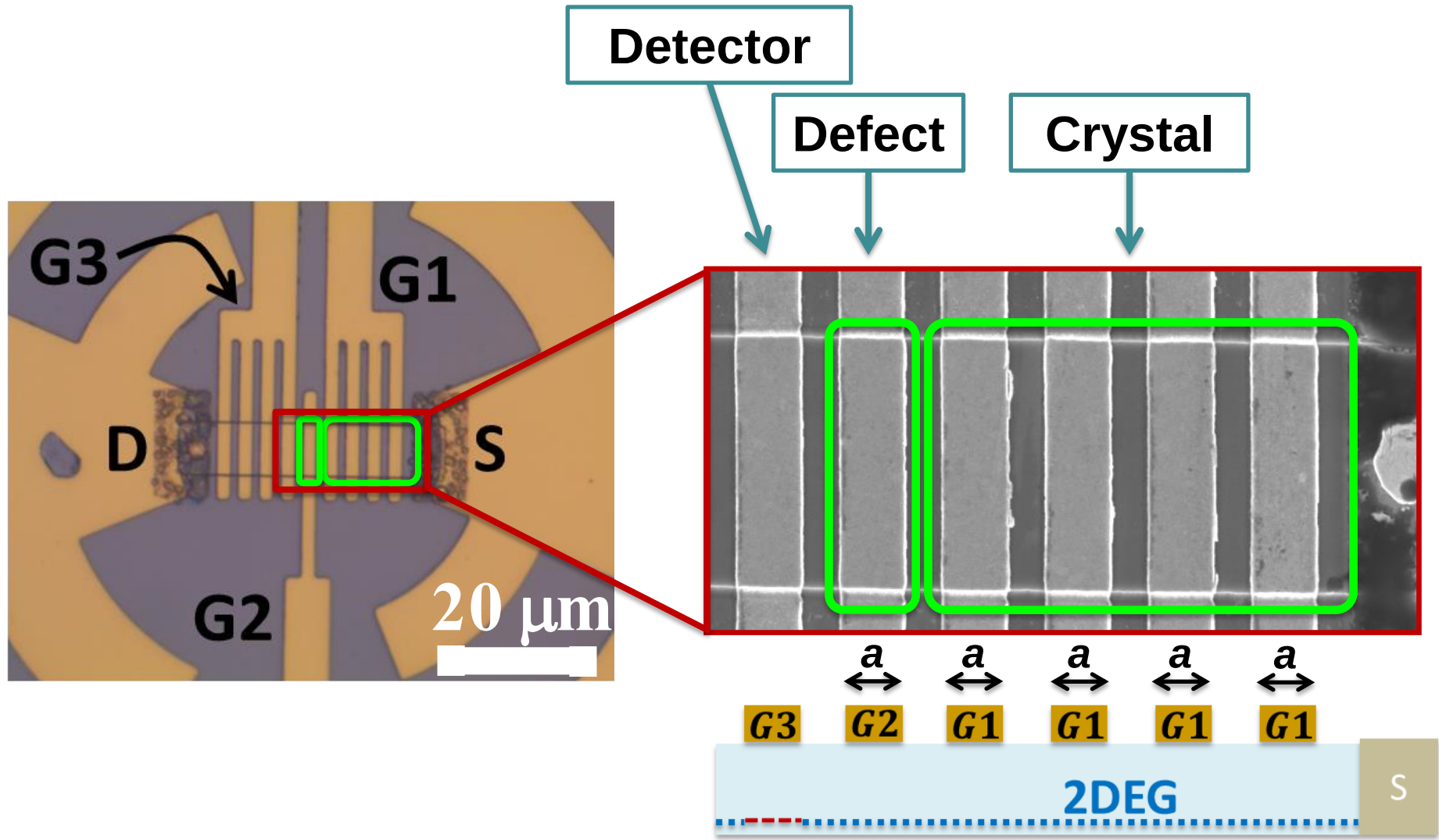
$$V_{G1} \rightarrow 0, L_1 \rightarrow \infty$$

Plasmonic Tamm States

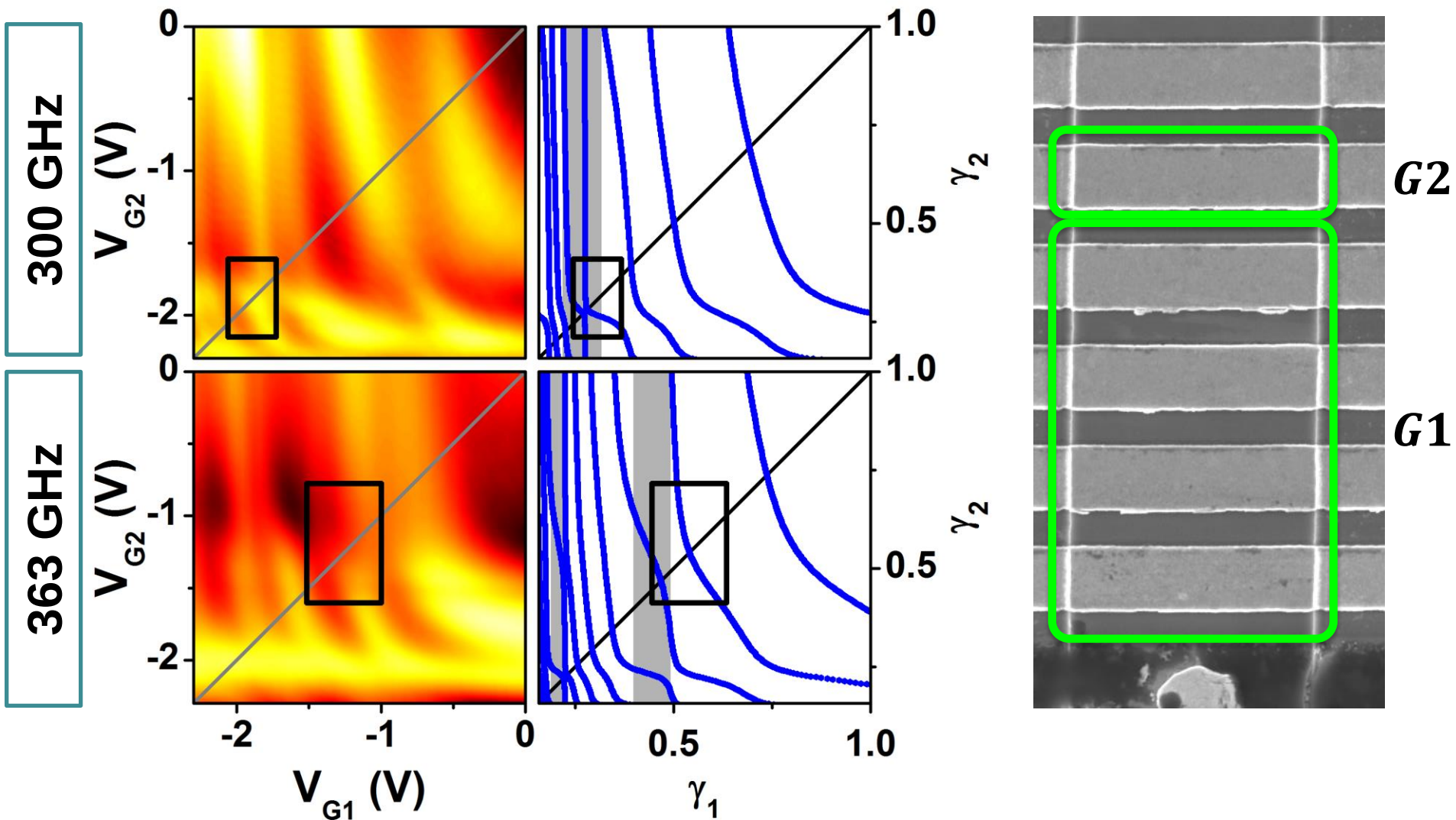


Crystal surface states typically found in crystal band gap that have complex Bloch wavevector ($Im[k_B] \neq 0$)

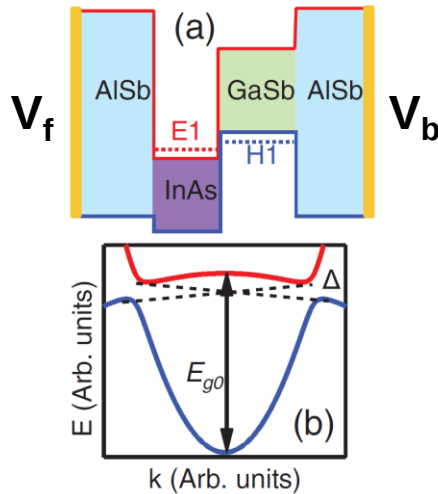
Defect Probing of Tamm States



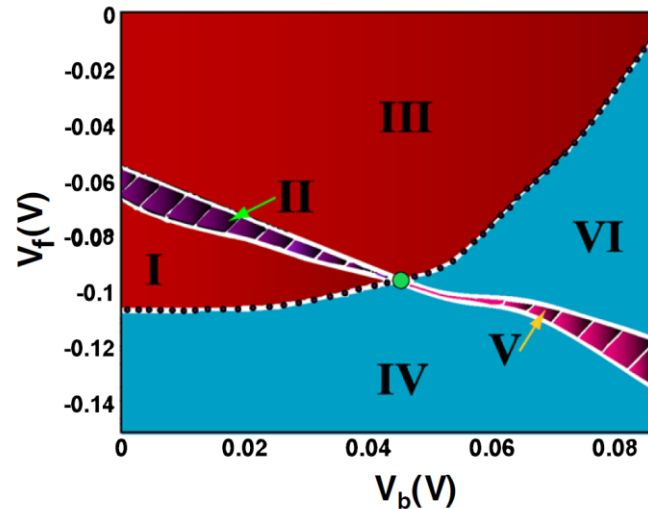
Coupled Tamm & Defect States



Quantum Spin Hall Insulators



Knez et al., *Phys. Rev. Lett.*,
107, 136603 (2011)



C. Liu et al., *Phys. Rev. Lett.*,
100, 236601 (2008)

Inverted Band Structure

I: $p > n$

II: QSH phase

III: $n > p$

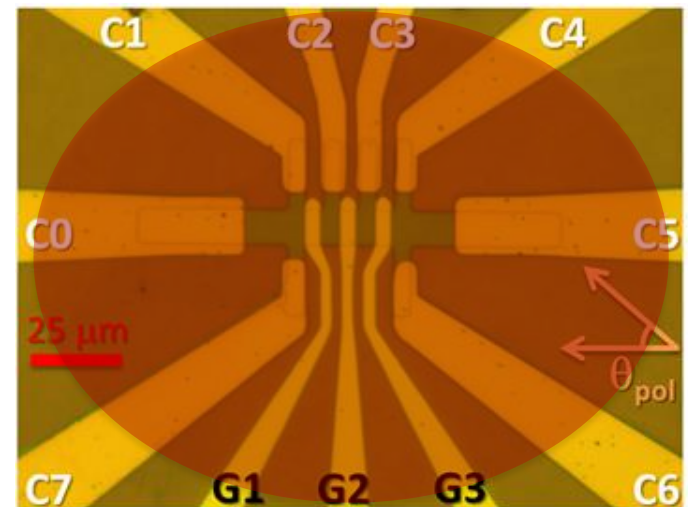
Normal Band Structure
IV-VI: p-type, insulating, n-type

Direct Current Phenomenology

- Spin Polarized Helical Edge Transport
- Quantized Conductance

Terahertz Response

- Lateral p-n rectifiers ?
- 2D plasmons ?
- Edge modes ?



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InAs/GaSb DQW Device

Longitudinal

V_{67}

V_{41}

Transverse

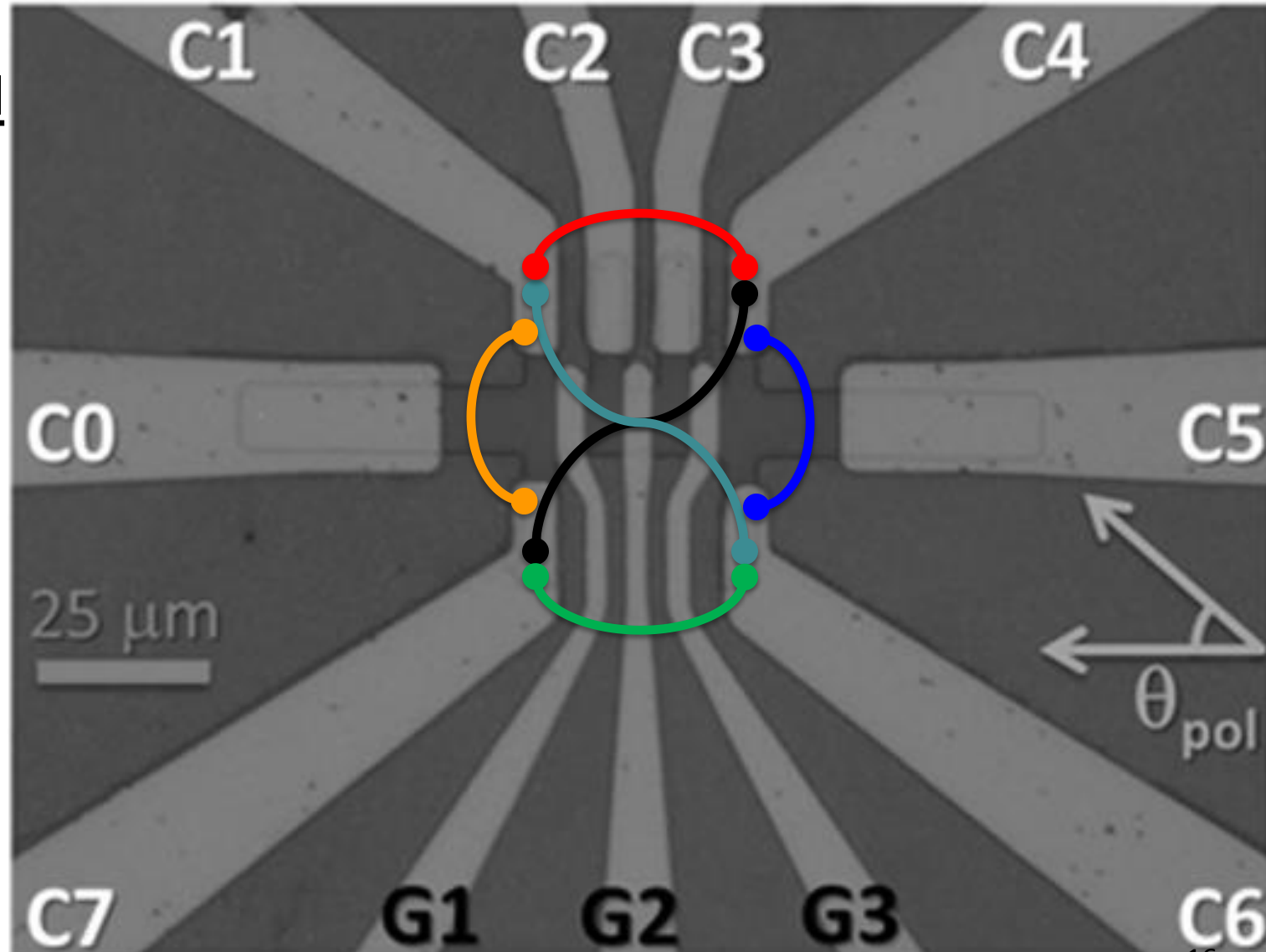
V_{46}

V_{17}

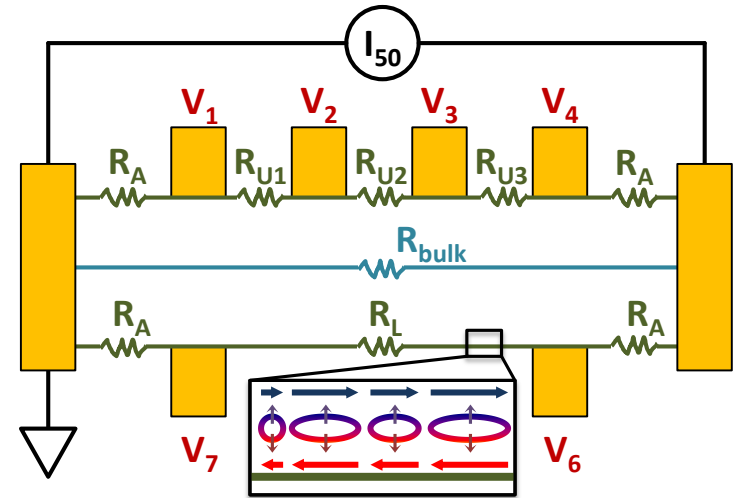
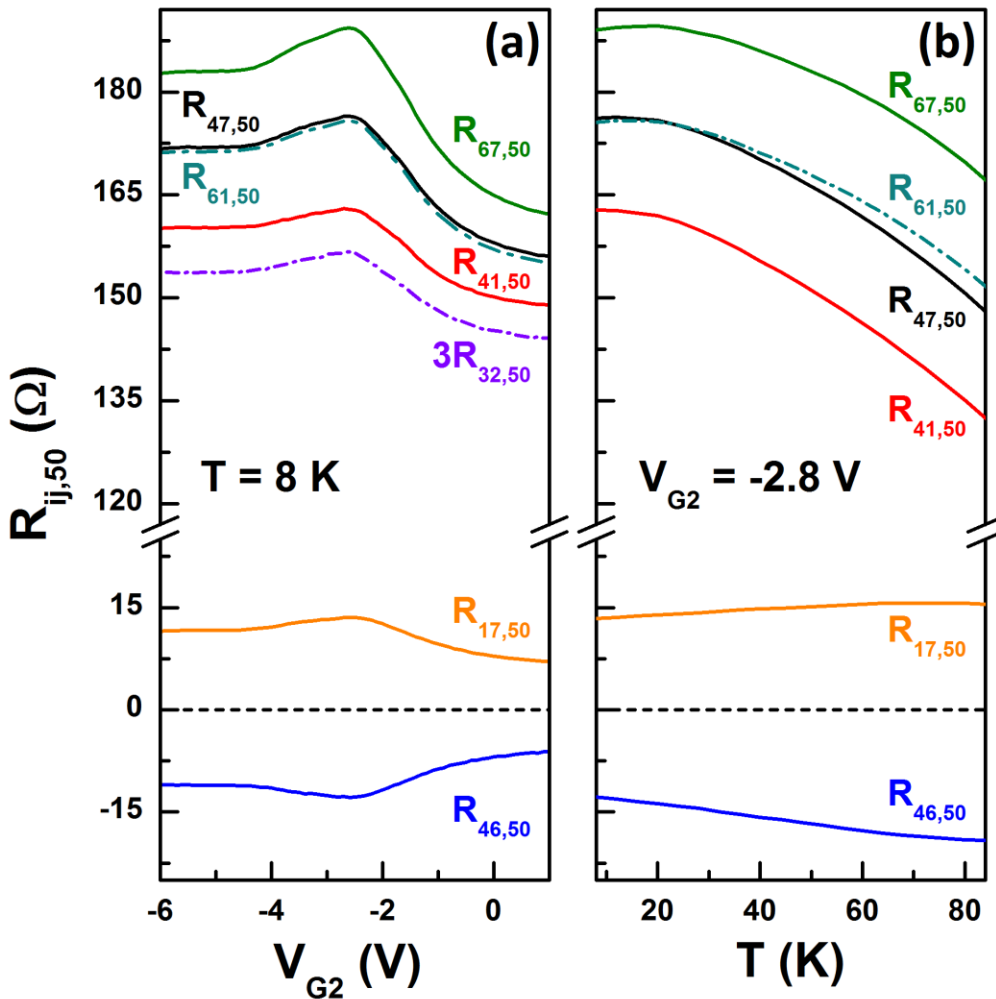
Diagonal

V_{47}

V_{61}

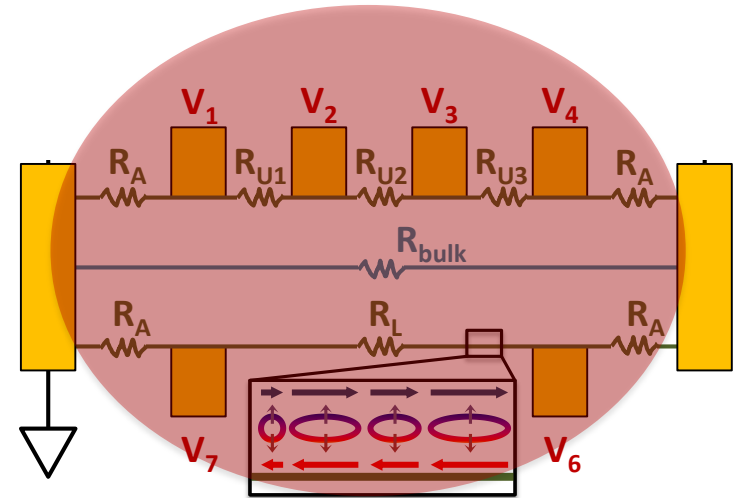
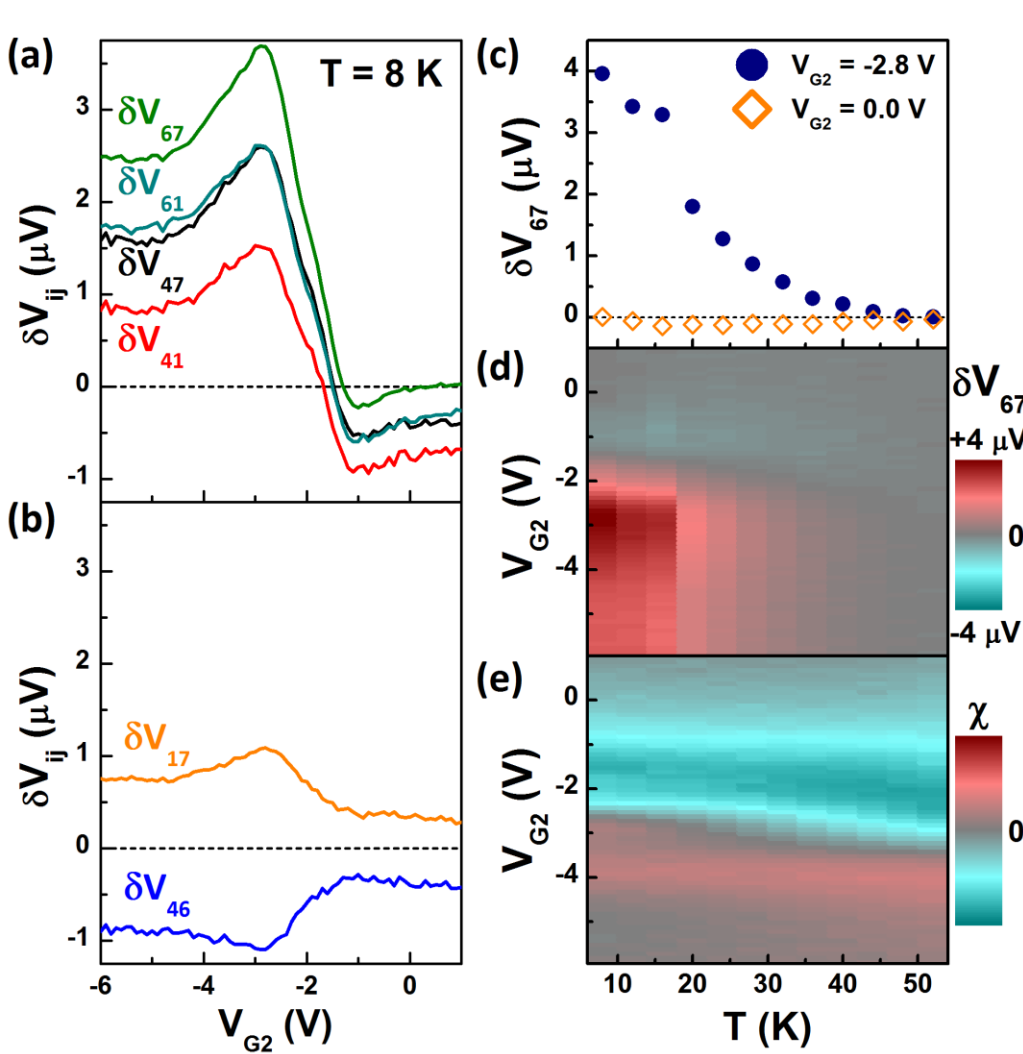


DC Transport



- Bulk dominant ($R_{ij} \ll 25.8 \text{ k}\Omega$)
- Longitudinal resistances (**green**, **red**) non-identical
- Mirrored transverse resistances (**blue**, **orange**) imply edge conduction
- $R_{67} > R_{41}$ indicates non-ballistic edge transport

180 GHz mm-Wave Response

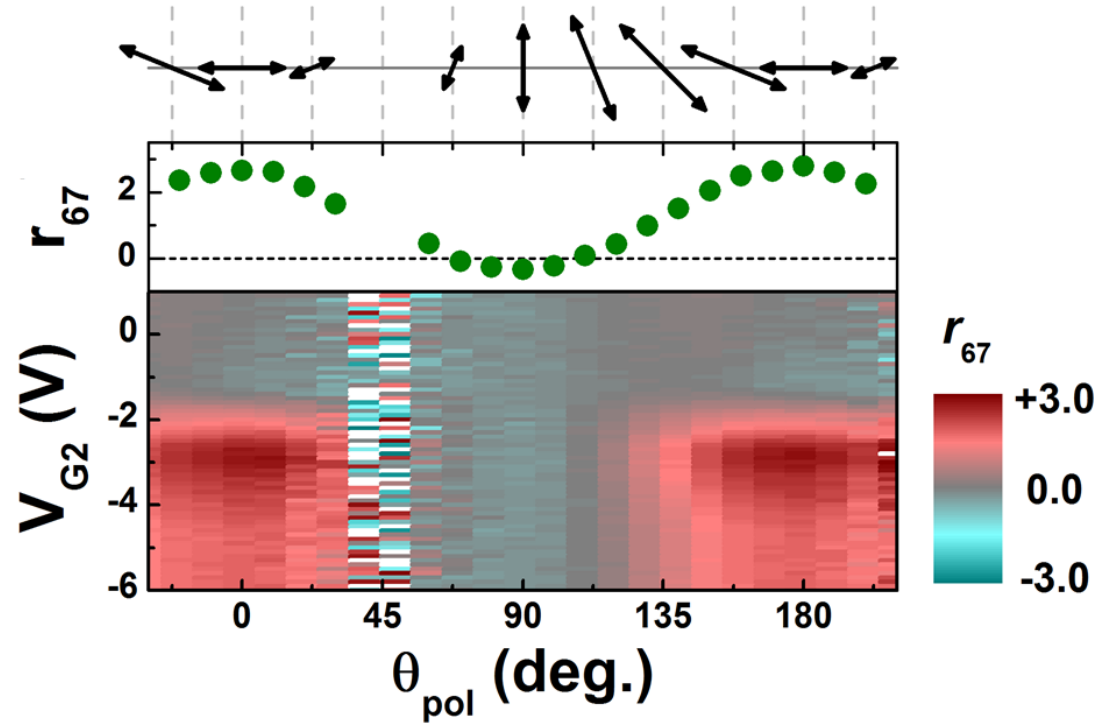


- Mirrored transverse signals(**blue**, **orange**) imply edge response
- Longitudinal (**green**, **red**) and diagonal (**black**, **teal**) signals similarly track DC behavior
- Not a bulk self-mixing response:

$$\chi \equiv R_{50,67} \frac{\partial(1/R_{50,67})}{\partial V_{G2}}$$

Polarization Sensitivity

- Signals peak with longitudinal THz field, $V_{G2} \sim V_{CNP}$
- Possibilities: DC photocurrent from AC excitation [1], rectification of 1D edge plasmons [2,3]



- [1] B. Dora, *et al.*, *PRL* **108**, 056602 (2012).
[2] O. Roslyak, *et al.*, *PRB* **87**, 045121 (2013).
[3] I. Appelbaum, *et al.*, *APL* **98**, 023103 (2011).

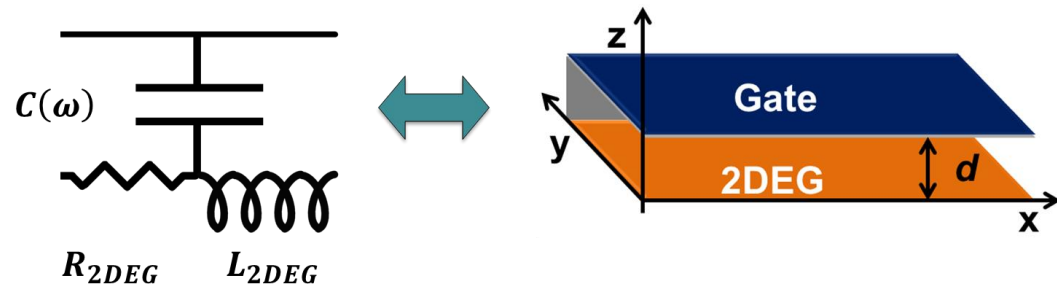
Conclusion: AC driving of edge currents in a material that supports QSH effect and a TI phase

Conclusions

Plasmonic cavity/waveguide

G.C. Dyer *et al.*, *APL* **100**, 083506 (2012)

G.C. Dyer *et al.*, *PRL* **109**, 126803 (2012)

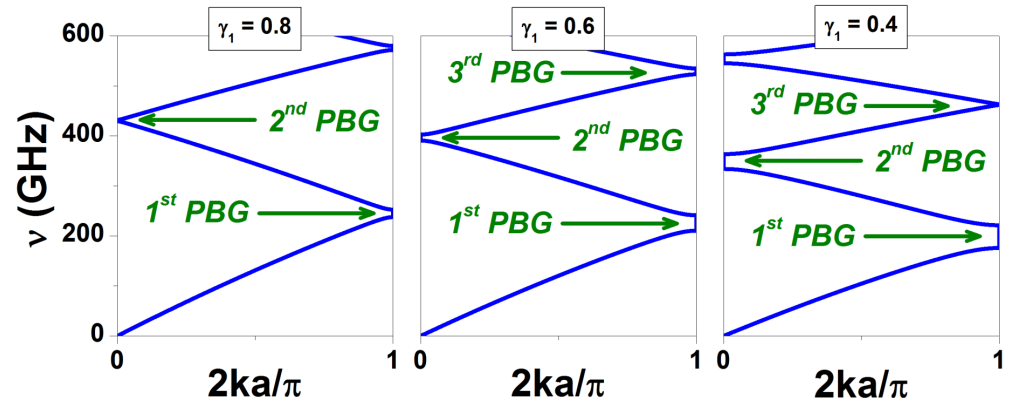


Active control of plasmonic dispersion

G.R. Aizin and G.C. Dyer, *PRB* **86**, 235316 (2012)

G.C. Dyer *et al.*, *Nature Photonics* **7**, 925 (2013)

G.C. Dyer *et al.*, *Opt. Expr.* **22**, 16254-16266 (2014)



Edge photoresponse in inverted DQWs

G.C. Dyer *et al.*, *APL* **108**, 013106 (2016)

